

## Metal Composite Power Inductor (Thin Film) Specification Sheet



## CIGT201610LM2R2MNE (2016 / EIA 0806)

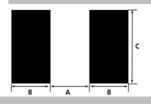
## ADDI ICATION

Smart phones, Tablet, Wearable devices, Power converter modules, etc.

## FFATURES

Small power inductor for mobile devices
Low DCR structure and high efficiency inductor for power circuits.
Monolithic structure for high reliability
Free of all RoHS-regulated substances
Halogen free

## RECOMMENDED LAND PATTERN



	Unit: mm
TYPE	2016
Α	0.8
В	0.8
С	1.8

## DIMENSION



TYPE	Dimension [mm]							
III	L	W	T	D				
2016	2.0±0.2	1.6±0.2	1.0 max	0.5±0.2				

## DESCRIPTION

Part no.	Size Thickness [mm] (max)	Thickness	Inductance	Inductance tolerance		ance [mΩ]	Rated DC Cu	rrent (Isat) [A]	Rated DC C	( -,
Part no.		[uH]	(%)	Max.	Тур.	Max.	Тур.	Max.	Тур.	
CIGT201610LM2R2MNE	0806/2016	1.0	2.2	±20	154	128	1.6	1.7	1.6	1.7

- \* Inductance : Measured with a LCR meter 4991A(Agilent) or equivalent (Test Freq. 1MHz, Level 0.1V)
- \* DC Resistance : Measured with a Resistance HI-TESTER 3541(HIOKI) or equivalent
- \* Maximum allowable DC current : Value defined when DC current flows and the initial value of inductance has decreased by 30% or when current flows and temperature has risen to 40 °C whichever is smaller. (Reference: ambient temperature is 25 °C±10)

(Isat) : Allowable current in DC saturation : The DC saturation allowable current value is specified when the decrease of

the initial inductance value at 30% (Reference: ambient temperature is 25 °C±10)

(Irms) : Allowable current of temperature rise : The temperature rise allowable current value is specified when temperature of the inductor is raised 40 ℃ by DC current. (Reference: ambient temperature is 25 ℃±10)

- \* Absolute maximum voltage : Absolute maximum voltage DC 20V.
- \* Operating temperature range : -40 to +125°C (Including self-temperature rise)

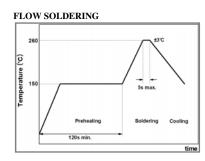
## PRODUCT IDENTIFICATION

<u>CIG</u>	<u>T</u>	<u>2016</u>	<u>10</u>	<u>LM</u>	<u>2R2</u>	<u>M</u>	<u>N</u>	<u>E</u>
(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)

- (1) Power Inductor
- (3) Dimensior (2016: 2.0mm ×1.6 mm )
- (5) Remark (Characterization Code)
- (7) Toleranc (M:±20%)
- (8) Internal Code
- (9) Packaging (C:paper tape, E:embossed tape)
- (2) Type (T: Metal Composite Thin Film Type)
- (4) Thicknes (10: 1.0mm)
- (6) Inductan (2R2: 2.2 uH)

## RECOMMENDED SOLDERING CONDITION

# REFLOW SOLDERING 260 230 100 max. Preheating Soldering Cooling 30 - 60s time



RON SOLDERING	
Temperature of Soldering Iron Tip	280 ℃ max.
Preheating Temperature	150°C min.
Temperature Differential	ΔT≤130℃
Soldering Time	3sec max.
Wattage	50W max.

## **PACKAGING**

Packaging Style	Quantity(pcs/reel)
Embossed Taping	3000 pcs

Item	Specified Value	Test Condition		
Solderability	More than 90% of terminal electrode should be soldered newly.	After being dipped in flux for $4\pm1$ seconds, and preheated at $150\sim180^{\circ}\!$		
Resistance to Soldering	No mechanical damage. Remaining terminal Electrode: 75% min. Inductance change to be within ±20% to the initial.	After being dipped in flux for 4±1 seconds, and preheated at $150 \sim 180^{\circ}$ for $2 \sim 3$ min, the specimen shall be immersed in solder at $260\pm5^{\circ}$ for $10\pm0.5$ seconds.		
Thermal Shock (Temperature Cycle test)	No mechanical damage Inductance change to be within ±20% to the initial.	Repeat 100 cycles under the following conditions40±3 $^{\circ}$ for 30 min $\rightarrow$ 85±3 $^{\circ}$ for 30 min		
High Temp. Humidity Resistance Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2℃, 85%RH, for 500±12 hours. Measure the test items after leaving at normal temperature and humidity for 24 hours.		
Low Temperature Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PCB. Exposure at -55±2°C for 500±12 hours.  Measure the test items after leaving at normal temperature and humidity for 24hours.		
High Temperature Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PCB. Exposure at 125±2°C for 500±12 hours.  Measure the test items after leaving at normal temperature and humidity for 24hours.		
High Temp. Humidity Resistance Loading Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, 85%RH, Rated Current for 500±12 hours.  Measure the test items after leaving at normal temperature and humidity for 24 hours.		
High Temperature Loading Test	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, Rated Current for 500±12 hours.  Measure the test items after leaving at normal temperature and humidity for 24 hours.		
Reflow Test	No mechanical damage Inductance change to be within ±20% to the initial	Peak 260±5℃, 3 times		
Vibration Test	No mechanical damage Inductance change to be within ±20% to the initial.	Solder the sample on PCB. Vibrate as apply 10~55Hz, 1.5mm amplitude for 2 hours in each of three(X,Y,Z) axis (total 6 hours).		
	No mechanical damage	Bending Limit; 2mm Test Speed; 1.0mm/sec. Keep the test board at the limit point in 5 sec. PCB thickness: 1.6mm		
Bending Test	19	20 Unit :mm  R340  46		
	No indication of peeling shall occur on the terminal electrode.	W(kgf) TIME(sec) 0.5 10±1		
Terminal Adhesion Test		W W		
Drop Test	No mechanical damage Inductance change to be within ±20% to the initial.	Random Free Fall test on concrete plate. 1 meter, 10 drops		
lpeak (AC+DC Load Life)	No mechanical damage Inductance change to be within ±20% to the initial	85±2°C, 85%RH, Load(Ipeak) for 120 hours. (Frequncy:1MHz, Load(Ipeak):1.5hr on / 0.5hr off) Measure the test items after leaving at normal temperature and humidity for 24 hours. * Load(Ipeak) = Irms(max)×1.4		



## Metal Composite Power Inductor (Thin Film) Data Sheet



## 1. Model: CIGT201610LM2R2MNE

## 2. Description

Part no.	Size Thickness Inc [inch/mm] [mm] (max)	Thickness	Inductance tolerance		DC Resist	ance [mΩ]	Rated DC Cui	rrent (Isat) [A]	Rated DC C	urrent (Irms) \]
Part no.		[uH]	(%)	Max.	Тур.	Max.	Тур.	Max.	Тур.	
CIGT201610LM2R2MNE	0806/2016	1.0	2.2	±20	154	128	1.6	1.7	1.6	1.7

- \* Inductance : Measured with a LCR meter 4991A(Agilent) or equivalent (Test Freq. 1MHz, Level 0.1V)
- \* DC Resistance : Measured with a Resistance HI-TESTER 3541(HIOKI) or equivalent
- \* Maximum allowable DC current : Value defined when DC current flows and the initial value of inductance has decreased by 30% or when current flows and temperature has risen to 40 °C whichever is smaller. (Reference: ambient temperature is 25 °C±10)

(Isat) : Allowable current in DC saturation : The DC saturation allowable current value is specified when the decrease of the initial inductance value at 30% (Reference: ambient temperature is 25 °C±10)

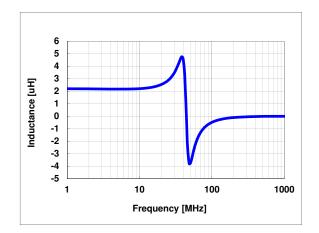
(Irms) : Allowable current of temperature rise : The temperature rise allowable current value is specified when temperature of the inductor is raised 40 ℃ by DC current. (Reference: ambient temperature is 25 ℃±10)

- \* Absolute maximum voltage : Absolute maximum voltage DC 20V.
- \* Operating temperature range : -40 to +125°C (Including self-temperature rise)

## 3. Characteristics data

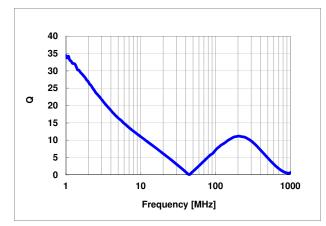
## 1) Frequency characteristics (Ls)

Agilent E4294A +E4991A , 1MHz to 1,000MHz

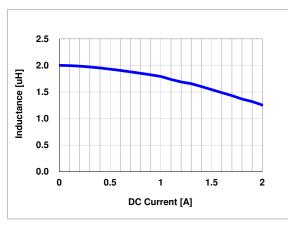


## 2) Frequency characteristics (Q)

Agilent E4294A +E4991A , 1MHz to 1,000MHz



## 3) DC Bias characteristics (Typ.)



## 4)Temperature characteristics (Typ.)

